0.5 A very low V_F MEGA Schottky barrier rectifiers

Rev. 01 — 29 November 2006

Produ

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in ultra small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
PMEG3005EB	SOD523	SC-79	single
PMEG3005EL	SOD882	-	single

1.2 Features

Forward current: I_F ≤ 0.5 A

Reverse voltage: V_R ≤ 30 V

Very low forward voltage

Ultra small SMD plastic packages

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 2. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \le 55 ^{\circ}C$	-	-	0.5	Α
V_R	reverse voltage		-	-	30	V
V_{F}	forward voltage	$I_F = 500 \text{ mA}$	<u>[1]</u> _	430	500	mV

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



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2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOD523			
1	cathode	[1]	8.4
2	anode		1 1 2
			sym001
SOD882			
1	cathode	<u>[1]</u>	8.4
2	anode		1 🔑 2
			sym001
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
PMEG3005EB	SC-79	plastic surface-mounted package; 2 leads	SOD523			
PMEG3005EL	-	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882			

4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG3005EB	KB
PMEG3005EL	AM

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5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	30	V
I _F	forward current	$T_{sp} \le 55 ^{\circ}C$	-	0.5	Α
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	1	Α
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	3	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u>		
	PMEG3005EB		-	310	mW
	PMEG3005EL		-	250	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-65	+150	°C
T_{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]			
	PMEG3005EB		-	-	400	K/W
	PMEG3005EL		-	-	500	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3]			
	PMEG3005EB		-	-	75	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Soldering point of cathode tab.

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7. Characteristics

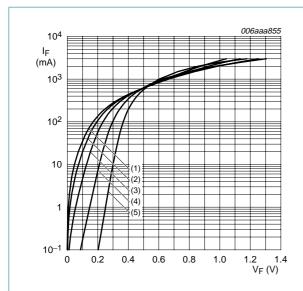
Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

· and — -		'				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	V _F forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	90	180	mV
	I _F = 1 mA	-	150	200	mV	
	I _F = 10 mA	-	210	270	mV	
		$I_F = 100 \text{ mA}$	-	295	360	mV
		$I_F = 500 \text{ mA}$	-	430	500	mV
I _R	reverse current	V _R = 10 V	-	15	200	μΑ
		V _R = 30 V	-	70	500	μΑ
C_d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$	-	24	30	pF

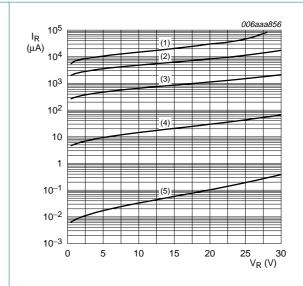
^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$.

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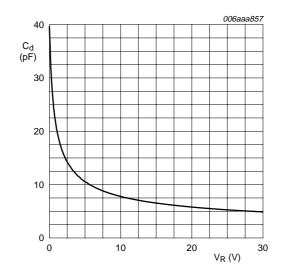
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \,^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \,^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

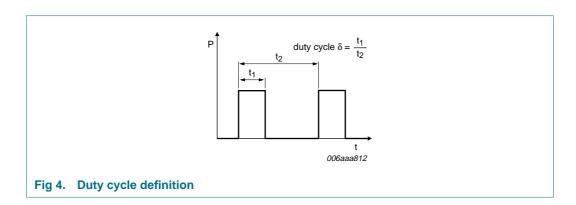


f = 1 MHz; T_{amb} = 25 °C

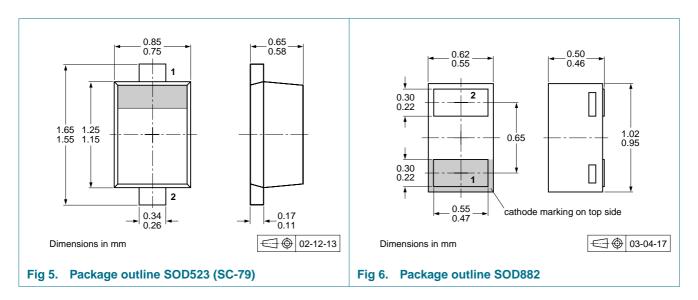
Fig 3. Diode capacitance as a function of reverse voltage; typical values

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8. Test information



9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

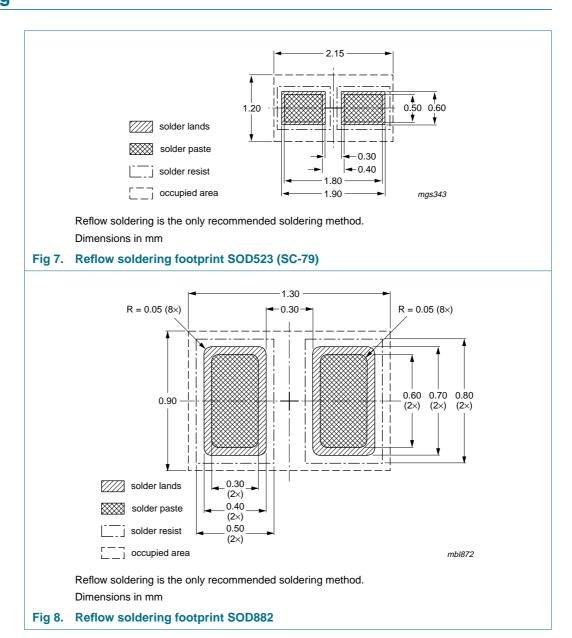
Type number	Package	Description	Packin	g quant	ity
			3000	8000	10000
PMEG3005EB	SOD523	2 mm pitch, 8 mm tape and reel	-	-315	-
		4 mm pitch, 8 mm tape and reel	-115	-	-135
PMEG3005EL	SOD882	2 mm pitch, 8 mm tape and reel	-	-	-315

^[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3005EB_PMEG3005EL_1	20061129	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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